CORRECTION

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Cite this: *RSC Adv.*, 2020, 10, 17571

Correction: Role of polysilicon in poly-Si/SiO_x passivating contacts for high-efficiency silicon solar cells

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DOI: 10.1039/d0ra90049d

rsc.li/rsc-advances

Correction for 'Role of polysilicon in poly-Si/SiO_x passivating contacts for high-efficiency silicon solar cells' by HyunJung Park *et al.*, *RSC Adv.*, 2019, 9, 23261–23266. DOI: 10.1039/c9ra03560e

The authors regret that the list of corresponding authors was incorrect in the original article. The corrected author list and associated contact details are as shown above.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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